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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/606,127	06/26/2003	Jin-Tae Kim	053785-5117	3643
9629 75	590 03/23/2005	EXAMINER		
MORGAN LEWIS & BOCKIUS LLP			WANG, GEORGE Y	
*****	LVANIA AVENUE NW		ART UNIT	PAPER NUMBER
WASHINGTO	N, DC 20004			THE DRIVEN DER
			2871	
			DATE MAILED: 03/23/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
		10/606,127	KIM ET AL.			
	Office Action Summary	Examiner	Art Unit			
	•	George Y. Wang	2871			
· ·	The MAILING DATE of this communication app					
Period fo	or Reply					
THE - Exte after - If the - If NO - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1.1: SIX (6) MONTHS from the mailing date of this communication. In a period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period ure to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be ting within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed vs will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \			
1)⊠	Responsive to communication(s) filed on 03 Ja	anuary 2005.				
2a)⊠	This action is FINAL . 2b) ☐ This	action is non-final.				
3)□	,— ,, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,					
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Disposit	ion of Claims					
5)□ 6)⊠ 7)⊠	Claim(s) <u>1-21</u> is/are pending in the application. 4a) Of the above claim(s) <u>11-21</u> is/are withdraw Claim(s) is/are allowed. Claim(s) <u>1-6,9 and 10</u> is/are rejected. Claim(s) <u>7 and 8</u> is/are objected to. Claim(s) are subject to restriction and/or	n from consideration.				
Applicati	ion Papers	,				
10)⊠	The specification is objected to by the Examine The drawing(s) filed on <u>26 June 2003</u> is/are: a) Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	\boxtimes accepted or b) \square objected to drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).			
Priority ι	under 35 U.S.C. § 119					
12)⊠ a)l	Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority documents application from the International Bureau See the attached detailed Office action for a list of	s have been received. s have been received in Application ity documents have been received (PCT Rule 17.2(a)).	on Noed in this National Stage			
Attachmen	t(s)					
1) Notic	e of References Cited (PTO-892)	4) Interview Summary				
3) 🔲 Inforr	e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) r No(s)/Mail Date	Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ate atent Application (PTO-152)			

DETAILED ACTION

Specification

1. Applicant's amended abstract filed January 3, 2005 is accepted by Examiner.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

3. Claims 1-6 and 9-10 are rejected under 35 U.S.C. 102(e) as being anticipated by Kwon et al. (U.S. Patent No. 6,671,010, hereinafter "Kwon").

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4. As to claim 1, Kwon discloses a liquid crystal display (LCD) device having an array substrate comprising a substrate (fig. 6j, ref. 100), a gate line (fig. 6i, ref. 102) and data line (fig. 6i, ref. 120) on the substrate that cross each other to define a pixel area (fig. 6e, ref. P), a thin film transistor (TFT) (fig. 6i, ref. T) electrically connected to the gate and date lines and including a gate electrode (fig. 6j, ref. 101), a source electrode (fig. 6j, ref. 112) over the gate electrode and connected to the data line, a drain electrode (fig. 6j, ref. 114) spaced apart (fig. 6i, ref. CH) from the source electrode, and a semiconductor layer (fig. 6f, ref. 116) having an active layer over the gate electrode, a first extended portion, and a neck region connecting the active layer and the first extended portion, wherein the neck region is completely covered with the drain electrode (see Response to Arguments), and a pixel electrode (fig. 6j, ref. 117) in the pixel region and connected (fig. 6j, ref. 119) to the drain electrode.

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- 5. Regarding claims 2-3, Kwon discloses the LCD as recited above where the source electrode has a U-shape (fig. 6i, ref. 112; col. 6, lines 55-59) and surrounds a part of the drain electrode (fig. 6i, ref. 114a), which has a rod shape.
- 6. As per claim 4, Kwon discloses the LCD as recited above further comprising a second extended portion (fig. 6e, ref. 116a) corresponding to the data line (fig. 6e, ref. 120) in the semiconductor layer.

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As to claims 5 and 9-10, Kwon discloses the LCD as recited above further comprising a doped semiconductor layer (fig. 6f, ref. 118) between the semiconductor layer (fig. 6f, ref. 116) and the source electrode (fig. 6f, ref. 112) and between the semiconductor layer (fig. 6f, ref. 116) and the drain electrode (fig. 6f, ref. 114a) in the TFT and where the semiconductor layer is formed of amorphous silicon and the doped semiconductor layer is formed of doped amorphous silicon (col. 9, lines 38-42).

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8. Regarding claim 6, Kwon discloses the LCD as recited above where the first extended portion at the boundary with the active layer has a width narrower than the active layer (fig. 6i, ref. M).

Allowable Subject Matter

9. Claims 7-8 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

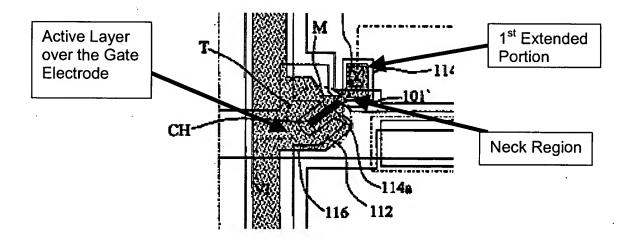
The following is a statement of reasons for the indication of allowable subject matter: The prior art of record fails to specifically disclose an LCD device particularly having a first extended portion where the width at the boundary with the active layer is in the range of about 2.8 μ m to about 3.4 μ m and where the drain electrode completely covering the first extended portion at the boundary with the active layer has a width in a range of about 4.5 μ m to about 5.6 μ m.

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Response to Arguments

10. Applicant's arguments filed January 3, 2005 have been fully considered but they are not persuasive.

Applicant's only argument is that the primary Kwon reference does not teach the claimed feature of "a semiconductor layer having an active layer over the gate electrode, a first extended portion, and a neck region connection the active layer and the first extended portion, wherein the neck region is completely covered with the drain electrode." Applicant's only support for this argument is the mere assertion that "Kwon et al does not show a cross-sectional structure taken along the line IX-XI of Fig. 7 of the present invention." However, Examiner disagrees. The Kwon reference clearly teaches a semiconductor layer (fig. 6f, ref. 116) having an active layer (fig. 6i, see arrow) over the gate electrode, a first extended portion (fig. 6i, see arrow), and a neck region (fig. 6i, see arrow) connecting the active layer and the first extended portion, wherein the neck region is completely covered with the drain electrode (fig. 6i, see dotted circled area).



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Since Applicant has provided no further argument or support for how the Kwon reference fails to teach the claimed invention, Examiner holds to the validity of the references and maintains rejection.

Conclusion

11. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to George Y. Wang whose telephone number is 571-272-2304. The examiner can normally be reached on M-F, 8 am - 4:30 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert H. Kim can be reached on 571-272-2293. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

gw March 18, 2005 RUBERT H. KIM
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800